

<b>Notice of References Cited</b>	Application/Control No. 10/593,556		Applicant(s)/Patent Under Reexamination OHTAKI, MICHITAKA	
	Examiner KOURTNEY R. SALZMAN		Art Unit 1795	Page 1 of 1

#### U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
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#### FOREIGN PATENT DOCUMENTS

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#### NON-PATENT DOCUMENTS

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\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
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